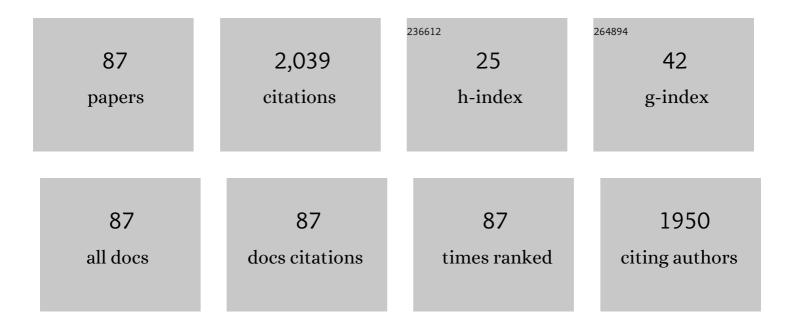
List of Publications by Year in descending order

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| # | Article | IF | CITATIONS |
|----|---|------|-----------|
| 1 | Development of a Methodology for Improving Photovoltaic Inverter Reliability. IEEE Transactions on Industrial Electronics, 2008, 55, 2581-2592. | 5.2 | 198 |
| 2 | Effect of Ag Particle Size in Thick-Film Ag Paste on the Electrical and Physical Properties of Screen Printed Contacts and Silicon Solar Cells. Journal of the Electrochemical Society, 2006, 153, A5. | 1.3 | 116 |
| 3 | Effect of glass frit chemistry on the physical and electrical properties of thick-film Ag contacts for silicon solar cells. Journal of Electronic Materials, 2006, 35, 2041-2047. | 1.0 | 115 |
| 4 | Superhydrophobic and Low Light Reflectivity Silicon Surfaces Fabricated by Hierarchical Etching. Langmuir, 2008, 24, 10421-10426. | 1.6 | 104 |
| 5 | High-Throughput Ion-Implantation for Low-Cost High-Efficiency Silicon Solar Cells. Energy Procedia, 2012, 15, 10-19. | 1.8 | 92 |
| 6 | Hybridizing ZnO Nanowires with Micropyramid Silicon Wafers as Superhydrophobic Highâ€Efficiency Solar Cells. Advanced Energy Materials, 2012, 2, 47-51. | 10.2 | 89 |
| 7 | Gettering and hydrogen passivation of edgeâ€defined filmâ€fed grown multicrystalline silicon solar cells by Al diffusion and forming gas anneal. Applied Physics Letters, 1994, 64, 97-99. | 1.5 | 79 |
| 8 | Large area tunnel oxide passivated rear contact <i>n</i> â€ŧype Si solar cells with 21.2% efficiency. Progress in Photovoltaics: Research and Applications, 2016, 24, 830-835. | 4.4 | 78 |
| 9 | Hierarchical robust textured structures for large scale self-cleaning black silicon solar cells. Nano Energy, 2014, 3, 127-133. | 8.2 | 71 |
| 10 | Understanding the Formation and Temperature Dependence of Thick-Film Ag Contacts on High-Sheet-Resistance Si Emitters for Solar Cells. Journal of the Electrochemical Society, 2005, 152, G742. | 1.3 | 69 |
| 11 | Chemical etching of boron-rich layer and its impact on high efficiency n-type silicon solar cells. Applied Physics Letters, 2012, 101, 073902. | 1.5 | 44 |
| 12 | 26.7% Efficient 4-Terminal Perovskite–Silicon Tandem Solar Cell Composed of a High-Performance Semitransparent Perovskite Cell and a Doped Poly-Si/SiOx Passivating Contact Silicon Cell. IEEE Journal of Photovoltaics, 2020, 10, 417-422. | 1.5 | 40 |
| 13 | Optimization of SiN AR coating for Si solar cells and modules through quantitative assessment of optical and efficiency loss mechanism. Progress in Photovoltaics: Research and Applications, 2011, 19, 983-990. | 4.4 | 38 |
| 14 | Hydrogen diffusion in silicon from plasma-enhanced chemical vapor deposited silicon nitride film at high temperature. Applied Physics Letters, 2008, 92, . | 1.5 | 37 |
| 15 | Fabrication and Modeling of High-Efficiency Front Junction N-Type Silicon Solar Cells With Tunnel Oxide Passivating Back Contact. IEEE Journal of Photovoltaics, 2017, 7, 1236-1243. | 1.5 | 36 |
| 16 | N-Type, Ion-Implanted Silicon Solar Cells and Modules. IEEE Journal of Photovoltaics, 2011, 1, 123-129. | 1.5 | 34 |
| 17 | High-Efficiency Large-Area Rear Passivated Silicon Solar Cells With Local Al-BSF and Screen-Printed Contacts. IEEE Journal of Photovoltaics, 2011, 1, 16-21. | 1.5 | 33 |
| 18 | Understanding and Use of IR Belt Furnace for Rapid Thermal Firing of Screen-Printed Contacts to Si Solar Cells. IEEE Electron Device Letters, 2010, 31, 461-463. | 2.2 | 30 |

| # | Article | IF | CITATIONS |
|----|---|-----|-----------|
| 19 | 20% Efficient Screen-Printed n-Type Solar Cells Using a Spin-On Source and Thermal Oxide/Silicon Nitride Passivation. IEEE Journal of Photovoltaics, 2011, 1, 146-152. | 1.5 | 30 |
| 20 | High-efficiency (19%) screen-printed textured cells on low-resistivity float-zone silicon with high sheet-resistance emitters. Progress in Photovoltaics: Research and Applications, 2006, 14, 135-144. | 4.4 | 28 |
| 21 | Fully screen-printed bifacial large area 22.6% N-type Si solar cell with lightly doped ion-implanted boron emitter and tunnel oxide passivated rear contact. Solar Energy Materials and Solar Cells, 2020, 214, 110585. | 3.0 | 28 |
| 22 | Bulk lifetime and efficiency enhancement due to gettering and hydrogenation of defects during cast multicrystalline silicon solar cell fabrication. Solid-State Electronics, 2008, 52, 612-617. | 0.8 | 27 |
| 23 | Evaluation of a Silicon 90Sr Betavoltaic Power Source. Scientific Reports, 2016, 6, 38182. | 1.6 | 27 |
| 24 | Screen printed, large area bifacial N-type back junction silicon solar cells with selective phosphorus front surface field and boron doped poly-Si/SiOx passivated rear emitter. Applied Physics Letters, 2018, 113, . | 1.5 | 27 |
| 25 | High efficiency inline diffused emitter (ILDE) solar cells on monoâ€crystalline CZ silicon. Progress in Photovoltaics: Research and Applications, 2010, 18, 590-595. | 4.4 | 26 |
| 26 | Hydrogenation of defects in edge-defined film-fed grown aluminum-enhanced plasma enhanced chemical vapor deposited silicon nitride multicrystalline silicon. Journal of Applied Physics, 2000, 87, 7551-7557. | 1.1 | 23 |
| 27 | High-efficiency screen-printed silicon ribbon solar cells by effective defect passivation and rapid thermal processing. Applied Physics Letters, 2003, 82, 224-226. | 1.5 | 23 |
| 28 | Investigation of Modified Screen-Printing Al Pastes for Local Back Surface Field Formation. , 2006, , . | | 22 |
| 29 | Modeling the potential of screen printed front junction CZ silicon solar cell with tunnel oxide passivated back contact. Progress in Photovoltaics: Research and Applications, 2017, 25, 49-57. | 4.4 | 22 |
| 30 | Ion-Implanted Screen-Printed n-Type Solar Cell With Tunnel Oxide Passivated Back Contact. IEEE Journal of Photovoltaics, 2016, 6, 153-158. | 1.5 | 21 |
| 31 | Tunnel oxide passivated rear contact for large area n -type front junction silicon solar cells providing excellent carrier selectivity. AIMS Materials Science, 2016, 3, 180-189. | 0.7 | 21 |
| 32 | Bulk resistivity optimization for low-bulk-lifetime silicon solar cells. Progress in Photovoltaics: Research and Applications, 2001, 9, 273-285. | 4.4 | 18 |
| 33 | High efficiency large area n -type front junction silicon solar cells with boron emitter formed by screen printing technology. Progress in Photovoltaics: Research and Applications, 2015, 23, 119-123. | 4.4 | 18 |
| 34 | A novel computer based pseudoâ€logarithmic capacitance/conductance DLTS system specifically designed for transient analysis. Review of Scientific Instruments, 1992, 63, 5733-5741. | 0.6 | 17 |
| 35 | Design Considerations for Large Roof-integrated Photovoltaic Arrays. Progress in Photovoltaics: Research and Applications, 1997, 5, 55-67. | 4.4 | 17 |
| 36 | Analytical approximation of effective surface recombination velocity of dielectric-passivated p-type silicon. Solid-State Electronics, 2001, 45, 1549-1557. | 0.8 | 17 |

| # | Article | IF | CITATIONS |
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| 37 | Improved front side metallization for silicon solar cells by direct printing. , 2011, , . | | 17 |
| 38 | Capitalizing on the Glass-Etching Effect of Silver Plating Chemistry to Contact Si Solar Cells With Homogeneous 100–110 \$Omega/hbox{sq}\$ Emitters. IEEE Electron Device Letters, 2011, 32, 779-781. | 2.2 | 16 |
| 39 | Approaching efficiencies above 25% with both sides-contacted silicon solar cells. , 2015, , . | | 16 |
| 40 | P-Type Indium-Doped Passivated Emitter Rear Solar Cells (PERC) on Czochralski Silicon Without Light-Induced Degradation. IEEE Journal of Photovoltaics, 2016, 6, 795-800. | 1.5 | 15 |
| 41 | On the Ink Jetting of Full Front Ag Gridlines for Cost-Effective Metallization of Si Solar Cells. IEEE Electron Device Letters, 2012, 33, 637-639. | 2.2 | 14 |
| 42 | Abnormal Dopant Distribution in \$hbox{POCl}_{3}\$-Diffused \$hbox{N}^{+}\$ Emitter of Textured Silicon Solar Cells. IEEE Electron Device Letters, 2011, 32, 351-353. | 2.2 | 13 |
| 43 | High-Efficiency n-Type Si Solar Cells With Novel Inkjet-Printed Boron Emitters. IEEE Electron Device Letters, 2012, 33, 854-856. | 2.2 | 13 |
| 44 | High efficiency screen-printed n-type silicon solar cell using co-diffusion of APCVD boron emitter and POCI 3 back surface field. Current Applied Physics, 2018, 18, 231-235. | 1.1 | 13 |
| 45 | Spatial profiles of photon chemical potential in near-field thermophotovoltaic cells. Journal of Applied Physics, 2021, 129, . | 1.1 | 13 |
| 46 | Sensitivity analysis of two-spectrum separation of surface and bulk components of minority carrier lifetimes. Solid-State Electronics, 2002, 46, 859-866. | 0.8 | 12 |
| 47 | Study of degradation in bulk lifetime of n-type silicon wafer due to oxidation of boron-rich layer. Current Applied Physics, 2016, 16, 497-500. | 1.1 | 12 |
| 48 | Fabrication and analysis of high-efficiency String Ribbon Si solar cells. Solid-State Electronics, 2006, 50, 1406-1412. | 0.8 | 11 |
| 49 | Process development and comparison of various boron emitter technologies for high-efficiency (~21%) n-type silicon solar cells. Progress in Photovoltaics: Research and Applications, 2016, 24, 1109-1115. | 4.4 | 11 |
| 50 | A Novel Processing Technology for Highâ€Efficiency Silicon Solar Cells. Journal of the Electrochemical Society, 1999, 146, 1141-1146. | 1.3 | 9 |
| 51 | 20.7% efficient ionâ€implanted large area <i>n</i> â€type front junction silicon solar cells with rear point contacts formed by laser opening and physical vapor deposition. Progress in Photovoltaics: Research and Applications, 2014, 22, 1030-1039. | 4.4 | 9 |
| 52 | Development of a simple analytical model to quantify the PV module cost premium associated with module efficiency and cell technology. Renewable and Sustainable Energy Reviews, 2014, 37, 380-385. | 8.2 | 9 |
| 53 | High-efficiency screen-printed belt co-fired solar cells on cast multicrystalline silicon. Applied Physics Letters, 2005, 86, 054103. | 1.5 | 7 |
| 54 | Carrier selective tunnel oxide passivated contact enabling 21.4% efficient large-area N-type silicon solar cells. , 2016, , . | | 7 |

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|----|--|-----|-----------|
| 55 | A Novel Approach Toward the Simultaneous Diffusion of Boron and Phosphorus in Silicon. Journal of the Electrochemical Society, 1997, 144, 346-349. | 1.3 | 6 |
| 56 | High-efficiency screen-printed solar cell on edge-defined film-fed grown ribbon silicon through optimized rapid belt co-firing of contacts and high-sheet-resistance emitter. Applied Physics Letters, 2004, 84, 3409-3411. | 1.5 | 6 |
| 57 | Development and Understanding of High-Efficiency Screen-Printed Concentrator Silicon Solar Cells. IEEE Journal of Photovoltaics, 2011, 1, 231-235. | 1.5 | 6 |
| 58 | Reduction in Light Induced Degradation (LID) in B-doped Cz-Si Solar Cells with SiCxNy Antireflection (AR) Coating. Journal of the Electrochemical Society, 2011, 158, H724. | 1.3 | 6 |
| 59 | Comparison of light-induced degradation and regeneration in P-type monocrystalline full aluminum back surface field and passivated emitter rear cells. Current Applied Physics, 2018, 18, 1600-1604. | 1.1 | 6 |
| 60 | Design, Optimization, and In-Depth Understanding of Front and Rear Junction Double-Side Passivated Contacts Solar Cells. IEEE Journal of Photovoltaics, 2021, 11, 1141-1148. | 1.5 | 6 |
| 61 | Understanding of High-Throughput Rapid Thermal Firing of Screen-Printed Contacts to Large-Area Cast Multicrystalline Si Solar Cells. IEEE Transactions on Electron Devices, 2010, 57, 2872-2879. | 1.6 | 5 |
| 62 | Understanding and Fabrication of 20% Efficient Cells Using Spin-on-Based Simultaneous Diffusion and Dielectric Passivation. IEEE Journal of Photovoltaics, 2012, 2, 22-26. | 1.5 | 5 |
| 63 | High efficiency screen printed low-medium concentrator silicon solar cells with direct printed 50µm wide fingers. , 2012, , . | | 5 |
| 64 | Understanding and Development of Screen-Printed Front Metallization for High-Efficiency Low-to-Medium Concentrator Silicon Solar Cells. IEEE Journal of Photovoltaics, 2013, 3, 944-951. | 1.5 | 5 |
| 65 | Analysis of cast mono-crystalline ingot characteristics with applications to solar cells. , 2012, , . | | 4 |
| 66 | Laser Crystallization and Dopant Activation of a-Si:H Carrier-Selective Layer in TOPCon Si Solar Cells. IEEE Journal of Photovoltaics, 2020, 10, 1283-1289. | 1.5 | 4 |
| 67 | Sulfurization as a promising surface passivation approach for both n- and p-type Si. , 2020, , . | | 4 |
| 68 | Resistivity dependence of minority carrier lifetime and cell performance in p-type dendritic web silicon ribbon. Solid-State Electronics, 2001, 45, 1973-1978. | 0.8 | 3 |
| 69 | Investigation of the Effect of Resistivity and Thickness on the Performance of Cast Multicrystalline Silicon Solar Cells. , 2006, , . | | 3 |
| 70 | Development of high-efficiency large-area screen-printed solar cells on direct kerfless epitaxially grown monocrystalline Si wafer and structure. Progress in Photovoltaics: Research and Applications, 2016, 24, 1133-1141. | 4.4 | 3 |
| 71 | Screen Printed, Large Area Bifacial N-PERT cells with Tunnel Oxide Passivated Back Contact. , 2017, , . | | 3 |
| 72 | Analysis of the negative charges injected into a SiO 2 /SiN x stack using plasma charging technology for fieldâ€effect passivation on a boronâ€doped silicon surface. Progress in Photovoltaics: Research and Applications, 2021, 29, 54-63. | 4.4 | 3 |

Ајеет Конатсі

| # | Article | IF | CITATIONS |
|----|--|-----|-----------|
| 73 | Modeling and Understanding of Rear Junction Double-Side Passivated Contact Solar Cells with Selective Area TOPCon on Front. , 2021, , . | | 3 |
| 74 | Decade Performance of a Roof-Mounted Photovoltaic Array. , 2006, , . | | 2 |
| 75 | Two-dimensional dopant profiling in POCl <inf>3</inf> -diffused n+ emitter of textured silicon solar cells. , 2011, , . | | 2 |
| 76 | Simultaneous iron gettering and passivation of p-type monocrystalline silicon using a negatively charged aluminum-doped dielectric. Applied Physics Letters, 2012, 101, 252105. | 1.5 | 2 |
| 77 | Development and use of a simple numerical model to quantify the impact of key photovoltaics system parameters on the levelized cost of electricity. , 2012, , . | | 2 |
| 78 | Effect of carbon containing SiNx antireflection coating on the screen-printed contact and low illumination performance of silicon solar cell. Progress in Photovoltaics: Research and Applications, 2013, 21, 351-358. | 4.4 | 2 |
| 79 | Optimization of ultraviolet laser doping for crystalline silicon solar cells with a novel segmented selective emitter design. Progress in Photovoltaics: Research and Applications, 2013, 21, 141-147. | 4.4 | 2 |
| 80 | High-Efficiency Large-Area Screen-Printed Solar Cell on Epitaxial Thin Active Layer With Porous Si Back Reflector Using Standard Industrial Process. IEEE Journal of Photovoltaics, 2015, 5, 123-128. | 1.5 | 2 |
| 81 | Enhanced Stability of Exposed PECVD Grown Thin <i>n</i> ⁺ Poly-Si/SiO <i> _x </i> Passivating Contacts With Al ₂ O ₃ Capping Layer During High Temperature Firing. IEEE Journal of Photovoltaics, 2021, 11, 268-272. | 1.5 | 2 |
| 82 | Dopant diffused Si surface passivation by H ₂ S gas reaction and quinhydrone-methanol treatment. , 2021, , . | | 2 |
| 83 | Distributed renewable generation: Interconnection and performance. , 2009, , . | | 1 |
| 84 | Investigation of Atomic Layer Deposition Al ₂ O ₃ Passivation for Screen-Printed Large-Area Solar Cells. IEEE Journal of Photovoltaics, 2016, 6, 869-874. | 1.5 | 1 |
| 85 | Laser Crystallization and Dopant Activation for a-Si:H Film in Carrier-Selective Contacts for Silicon Solar cells. , 2019, , . | | 1 |
| 86 | High efficiency silicon solar cells. Solar Cells, 1988, 23, 273-274. | 0.6 | 0 |
| 87 | Study of lifetime degradation in n-type silicon due to oxidation of boron-rich layer. , 2013, , . | | Ο |